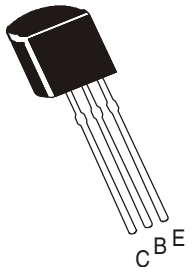
Continental Device India Limited

An ISO/TS16949 and ISO 9001 Certified Company

PNP SILICON PLANAR EPITAXIAL TRANSISTORS

BC212, A, B
BC213, A, B, C
BC214, B, C

TO-92
Plastic Package



Silicon Small Signal General Purpose Amplifier

ABSOLUTE MAXIMUM RATINGS (T_a=25ºC unless specified otherwise)

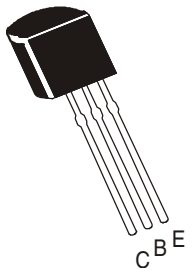
DESCRIPTION	SYMBOL	BC212	BC213	BC214	UNITS
Collector Emitter Voltage	V_{CEO}	50	30	30	V
Collector Base Voltage	V_{CBO}	60	45	45	V
Emitter Base Voltage	V_{EBO}		5		V
Collector Current Continuous	I_C		100		mA
Power Dissipation @ T_a=25ºC	P_D		350		mW
Derate Above 25ºC			2.8		mW/ ºC
Power Dissipation @ T_c=25ºC	P_D		1		W
Derate Above 25ºC			8		mW/ ºC
Operating And Storage Junction Temperature Range	T_j, T_{stg}	-55 to +150			ºC

THERMAL RESISTANCE

Junction to Ambient in free air	$R_{th\ (j-a)}$	357	ºC/W
Junction to case	$R_{th\ (j-c)}$	125	ºC/W

PNP SILICON PLANAR EPITAXIAL TRANSISTORS

BC212, A, B
BC213, A, B, C
BC214, B, C



TO-92
Plastic Package

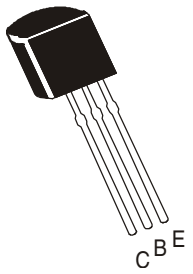
ELECTRICAL CHARACTERISTICS (T_a=25ºC unless specified otherwise)

DESCRIPTION	SYMBOL	TEST CONDITION	MIN	TYP	MAX	UNITS
Collector Emitter Voltage	V_{CEO}	I_C=2mA,I_B=0				
BC212			50			V
BC213, BC214			30			V
Collector Base Voltage	V_{CBO}	I_C=10uA.I_E=0				
BC212			60			V
BC213, BC214			45			V
Emitter Base Voltage	V_{EBO}	I_E=10uA, I_C=0	5			V
Collector Cut off Current	I_{CBO}	V_{CB}=30V,I_E=0			15	nA
Emitter Cut off Current	I_{EBO}	V_{EB}=4V, I_C=0			15	nA
DC Current Gain						
BC212, BC213	h_{FE}	I_C=10uA,V_{CE}=5V	40			
BC214			100			
BC212	h_{FE}	I_C=2mA,V_{CE}=5V	60			
BC213			80			
BC214			140		600	
BC212, BC214	h_{FE}	I_C=100mA,V_{CE}=5V*		120		
BC213				140		
Collector Emitter Saturation Voltage	$V_{CE(sat)}$	I_C=10mA,I_B=0.5mA		0.10		V
		I_C=100mA,I_B=5mA*		0.25	0.6	V
Base Emitter Saturation Voltage	$V_{BE(sat)}$	I_C=100mA,I_B=5mA*		1.00	1.4	V
Base Emitter On Voltage	$V_{BE(on)}$	I_C=2mA,V_{CE}=5V	0.6	0.62	0.72	V

***Pulse Condition: Pulse Width = 300μs, Duty Cycle = 2%.**

PNP SILICON PLANAR EPITAXIAL TRANSISTORS

BC212, A, B
BC213, A, B, C
BC214, B, C



TO-92
Plastic Package

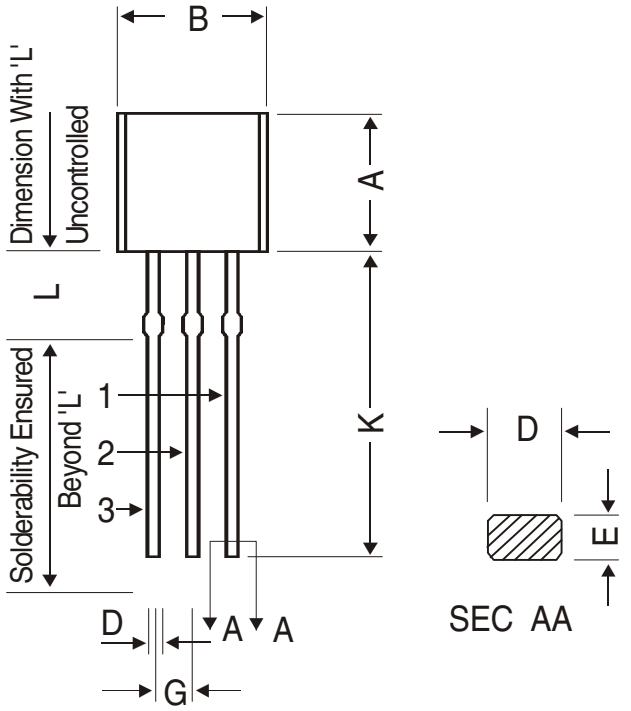
ELECTRICAL CHARACTERISTICS (T_a=25ºC unless specified otherwise)

DYNAMICS CHARACTERISTICS

DESCRIPTION	SYMBOL	TEST CONDITION	MIN	TYP	MAX	UNITS
Transition Frequency						
BC212	f_T	I_C=10mA, V_{CE}=5V		280		MHz
BC213		f=50MHz		360		MHz
BC214				320		MHz
Output Capacitance	C_{ob}	V_{CB}=10V, I_E=0			6	pF
Noise Figure						
BC212, BC213	NF	I_C=200uA, V_{CE}=5V			10	dB
		R_S=2KΩ f=1KHz				
		f=200H_Z				
BC214	NF	I_C=200uA, V_{CE}=5V			2	dB
		R_S=2KΩ f=30Hz				
		to 15KHz				
Small Signal Current Gain						
BC212	h_{fe}	I_C=2mA, V_{CE}=5V	60			
BC213		f=1KH_Z	80			
BC214			140			
BC212A, BC213A	h_{fe}	I_C=2mA, V_{CE}=5V	100		300	
BC212B, BC213B, BC214B		f=1KH_Z	200		400	
BC213C, BC214C			350		600	

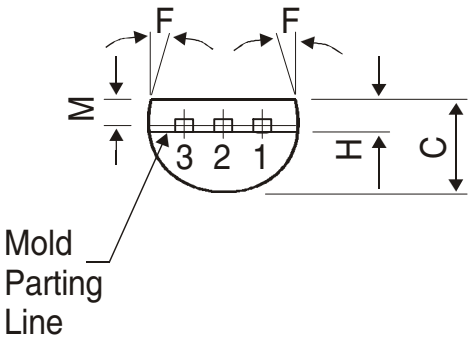
***Pulse Condition: Pulse Width = 300μs, Duty Cycle = 2%.**

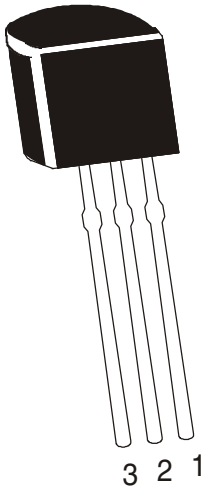
TO-92 Plastic Package



DIM	MIN.	MAX.
A	4.32	5.33
B	4.45	5.20
C	3.18	4.19
D	0.41	0.55
E	0.35	0.50
F	5 DEG	
G	1.14	1.40
H	1.20	1.40
K	12.70	—
L	1.982	2.082
M	1.03	1.20

All dimensions are in mm





PIN CONFIGURATION
1. EMITTER
2. BASE
3. COLLECTOR

The TO-92 Package , Tape and Ammo Pack drawings are correct as on the date of issue/revision of this Data Sheet.

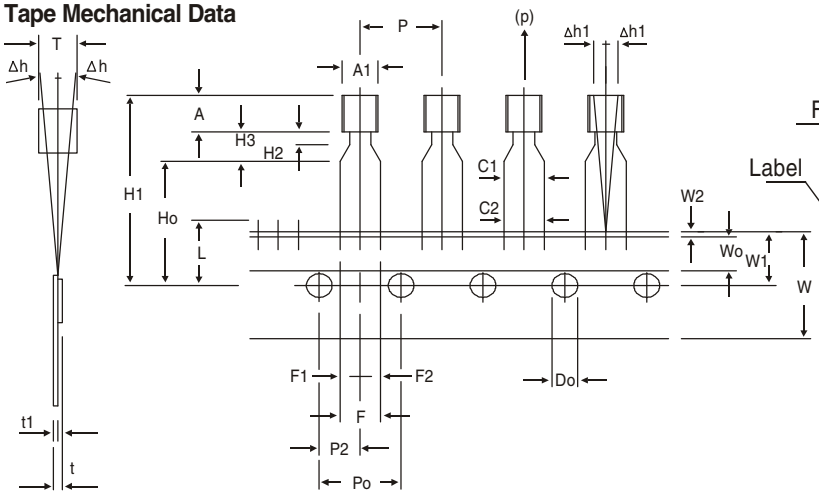
The currently valild dimensions and information, may please be confirmed from the TO-92 Drawing in the Packages and Packing Section of the Product Catalogue.

Packing Details

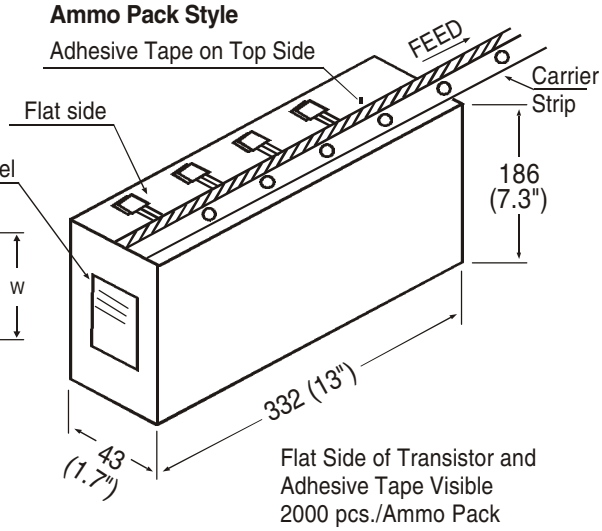
PACKAGE	STANDARD PACK		INNER CARTON BOX		OUTER CARTON BOX		
	Details	Net Weight/Qty	Size	Qty	Size	Qty	Gr Wt
TO-92 Bulk	1K/polybag	200 gm/1K pcs	3" x 7.5" x 7.5"	5K	17" x 15" x 13.5"	80K	23 kgs
TO-92 T&A	2K/ammo box	645 gm/2K pcs	12.5" x 8" x 1.8"	2K	17" x 15" x 13.5"	32K	12.5 kgs

TO-92 Tape and Ammo Pack

Tape Mechanical Data



Ammo Pack Style



Flat Side of Transistor and
Adhesive Tape Visible
2000 pcs./Ammo Pack

All dimensions are in mm

ITEM	SYMBOL	SPECIFICATION			
		MIN.	NOM.	MAX.	TOL .
BODY WIDTH	A1	4.0		4.8	
BODY HEIGHT	A	4.8		5.2	
BODY THICKNESS	T	3.9		4.2	
PITCH OF COMPONENT	P		12.7		± 1.0
*1 FEED HOLE PITCH	Po		12.7		± 0.3
*2 FEED HOLE CENTRE TO COMPONENT CENTRE	P2		6.35		± 0.4
DISTANCE BETWEEN OUTER LEADS	F		5.08		+ 0.6 - 0.2
*3 COMPONENT ALIGNMENT SIDE VIEW	△h		0	1.0	
*4 COMPONENT ALIGNMENT FRONT VIEW	△h1		0	1.3	
TAPE WIDTH	W		18		± 0.5
HOLD-DOWN TAPE WIDTH	Wo		6		± 0.2
HOLE POSITION	W1		9		+ 0.7 - 0.5
HOLD-DOWN TAPE POSITION	W2		0.5		± 0.2
LEAD WIRE CLINCH HEIGHT	Ho		16		± 0.5
COMPONENT HEIGHT	H1			23.25	
LENGTH OF SNIPPED LEADS	L			11.0	
FEED HOLE DIAMETER	Do		4		± 0.2
*5 TOTAL TAPE THICKNESS	t			1.2	
LEAD - TO - LEAD DISTANCE	F1, F2		2.54		+ 0.4 - 0.1
STAND OFF	H2	0.45		1.45	
CLINCH HEIGHT	H3			3.0	
LEAD PARALLELISM	| C1 - C2 |			0.22	
PULL - OUT FORCE	(p)	6N			

NOTES

1. Maximum alignment deviation between leads will not to be greater than 0.2mm.
2. Maximum non-cumulative variation between tape feed holes shall not exceed 1 mm in 20 pitches.
3. Holddown tape will not exceed beyond the edge(s) of carrier tape and there shall be no exposure of adhesive.
4. There will be no more than three (3) consecutive missing components in a tape.
5. A tape trailer, having at least three feed holes are provided after the last component in a tape.
6. Splices should not interfere with the sprocket feed holes.

REMARKS

*1 Cumulative pitch error 1.0 mm/20 pitch

*2 To be measured at bottom of clinch

*3 At top of body

*4 At top of body

*5 t1 0.3 – 0.6 mm

Disclaimer

The product information and the selection guides facilitate selection of the CDIL's Discrete Semiconductor Device(s) best suited for application in your product(s) as per your requirement. It is recommended that you completely review our Data Sheet(s) so as to confirm that the Device(s) meet functionality parameters for your application. The information furnished in the Data Sheet and on the CDIL Web Site/CD are believed to be accurate and reliable. CDIL however, does not assume responsibility for inaccuracies or incomplete information. Furthermore, CDIL does not assume liability whatsoever, arising out of the application or use of any CDIL product; neither does it convey any license under its patent rights nor rights of others. These products are not designed for use in life saving/support appliances or systems. CDIL customers selling these products (either as individual Discrete Semiconductor Devices or incorporated in their end products), in any life saving/support appliances or systems or applications do so at their own risk and CDIL will not be responsible for any damages resulting from such sale(s).

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